

FMH07N90E

FUJI POWER MOSFET

Super FAP-E³ series

N-CHANNEL SILICON POWER MOSFET

Features

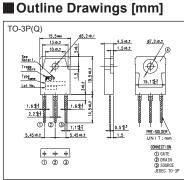
Maintains both low power loss and low noise Lower R_{DS}(on) characteristic More controllable switching dv/dt by gate resistance Smaller V_{GS} ringing waveform during switching Narrow band of the gate threshold voltage (4.0±0.5V) High avalanche durability

Applications

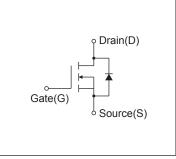
Switching regulators UPS (Uninterruptible Power Supply) **DC-DC converters**

Maximum Ratings and Characteristics

Absolute Maximum Ratings at Tc=25°C (unless otherwise specified)







Description	Symbol	Characteristics	Unit	Remarks
Drain Source Voltone	VDS	900	V	
Drain-Source Voltage	VDSX	900	V	V _{GS} = -30V
Continuous Drain Current	lo	±7	А	
Pulsed Drain Current	IDP	±28	А	
Gate-Source Voltage	Vgs	±30	V	
Repetitive and Non-Repetitive Maximum AvalancheCurrent	lar	7	А	Note*1
Non-Repetitive Maximum Avalanche Energy	Eas	396.3	mJ	Note*2
Repetitive Maximum Avalanche Energy	Ear	14.5	mJ	Note*3
Peak Diode Recovery dV/dt	dV/dt	2.1	kV/µs	Note*4
Peak Diode Recovery -di/dt	-di/dt	100	A/µs	Note*5
Mauinum Davies Diagingtian	PD	2.5	14/	Ta=25°C
Maximum Power Dissipation		145	W	Tc=25°C
	Tch	150	°C	
Operating and Storage Temperature range	Tstg	-55 to + 150	°C	

Electrical Characteristics at Tc=25°C (unless otherwise specified)

Description	Symbol	Conditions		min.	typ.	max.	Unit
Drain-Source Breakdown Voltage	BVDSS	ID=250µA, VGS=0V		900	-	-	V
Gate Threshold Voltage	V _{GS} (th)	ID=250µA, VDS=VGS		3.5	4.0	4.5	V
Zana Oata Maltana Durin Orimunt		V _{DS} =900V, V _{GS} =0V	Tch=25°C	-	-	25	μΑ
Zero Gate Voltage Drain Current	IDSS	VDS=720V, VGS=0V	Tch=125°C	-	-	250	
Gate-Source Leakage Current	Igss	V _{GS} =±30V, V _{DS} =0V		-	10	100	nA
Drain-Source On-State Resistance	RDS (on)	ID=3.5A, VGS=10V		-	1.65	2.0	Ω
Forward Transconductance	g _{fs}	ID=3.5A, VDS=25V	ID=3.5A, VDS=25V		8.4	-	S
Input Capacitance	Ciss	V _{DS} =25V - V _{GS} =0V - f=1MHz -		-	1200	1800	pF
Output Capacitance	Coss			-	115	175	
Reverse Transfer Capacitance	Crss			8.5	13		
Turn-On Time	td(on)	V _{cc} =600V V _{cs} =10V I _D =3.5A		-	33	53	ns
	tr			-	32	45	
	td(off)			-	110	165	
Turn-Off Time	tf Rc=36Ω	-	32	45			
Total Gate Charge	QG	- V _{cc} =450V I _D =7A V _{GS} =10V		-	39	59	nC
Gate-Source Charge	QGS			-	10	15	
Drain-Source Crossover Charge	Qsw			-	3.6	5.5	
Gate-Drain Charge	QGD			-	15	23	
Avalanche Capability	lav	L=5.93mH, T _{ch} =25°C		7	-	-	A
Diode Forward On-Voltage	Vsd	IF=7A, VGS=0V, Tch=25°C		-	0.90	1.35	V
Reverse Recovery Time	trr	IF=7A, VGS=0V		-	1.65	-	μS
Reverse Recovery Charge	Qrr	di/dt=100A/µs, Tch=25°C		-	11	-	μC

• Thermal Characteristics

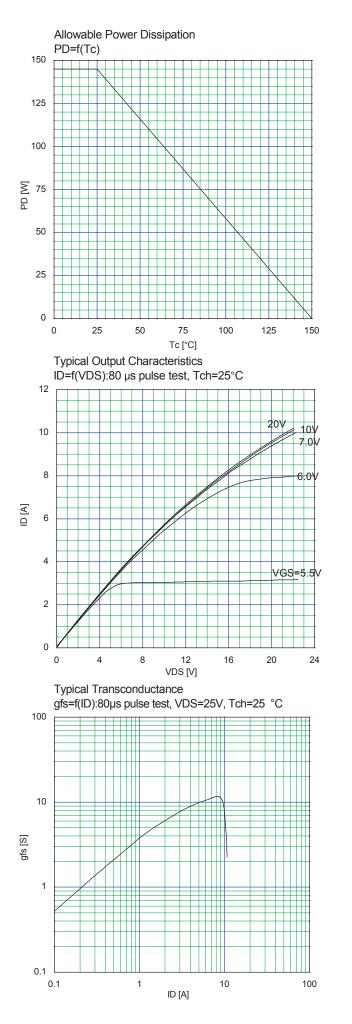
Description	Symbol	Test Conditions	min.	typ.	max.	Unit
Thermal resistance	Rth (ch-c)	Channel to case			0.862	°C/W
	Rth (ch-a)	Channel to ambient			50.0	°C/W

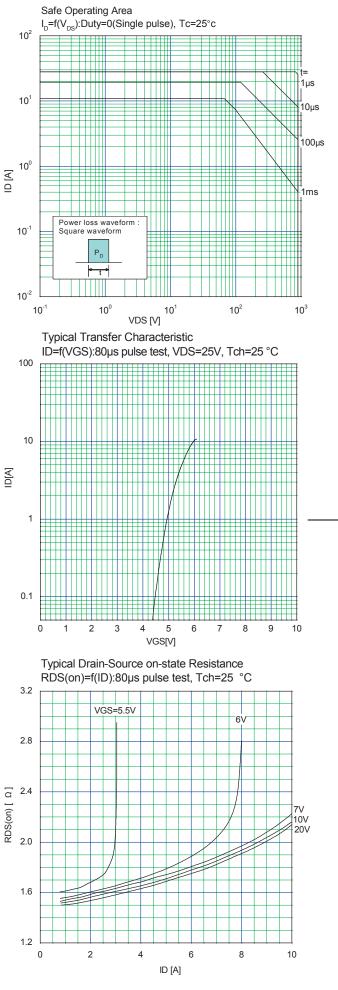
Note *1 : Tch≤150°C

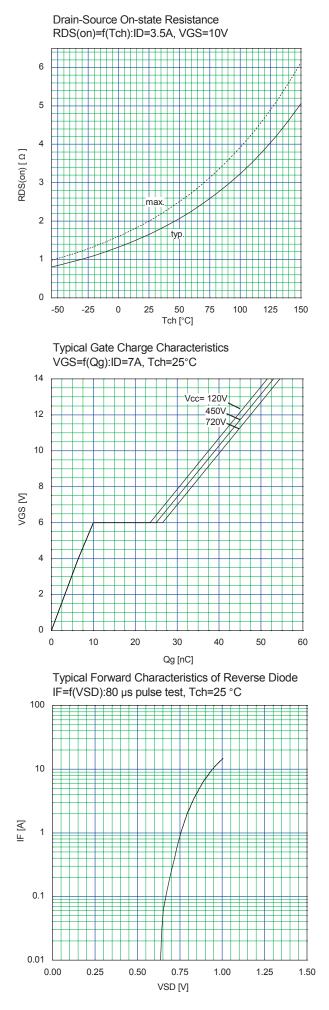
Note *2 : Stating Tch=25°C, I_{AS}=2.8A, L=92.7mH, Vcc=90V, R_{G}=10\Omega E_{As} limited by maximum channel temperature and avalanche current. See to 'Avalanche current' graph.

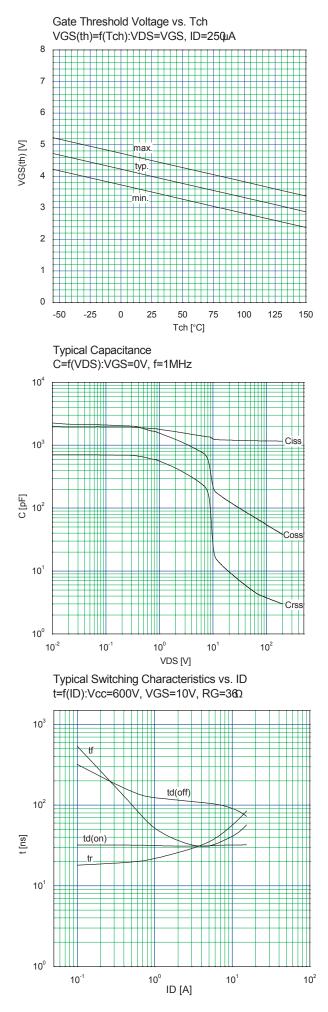
Note *3 : Repetitive rating : Pulse width limited by maximum channel temperature

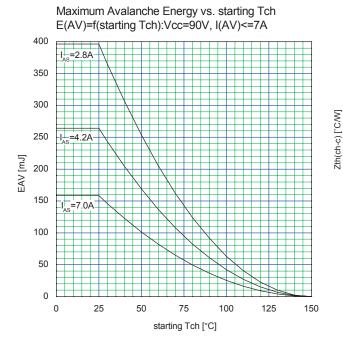
See to the 'Transient Themal impeadance' graph. Note *4 : Ir≤-Ip, -di/dt=100A/µs, Vcc≤BVpss, Tch≤150°C. Note *5 : Ir≤-Ip, dv/dt=2.1kV/µs, Vcc≤BVpss, Tch≤150°C.



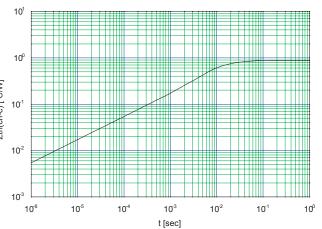








Maximum Transient Thermal Impedance Zth(ch-c)=f(t):D=0



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